

MDL-III-852/1~1500mW

INFRARED DIODE LASER AT 852nm

Diode infrared laser module at 852nm is made features of ultra compact, long lifetime, low cost and easy operating, which is used in measurement, communication, spectrum analysis, etc.



SPECIFICATIONS

Wavelength (nm)	852±10	
Operating mode	CW	
Output power (mW)	>1, 100, 200, 300, ..., 1500	
Power stability (rms, over 4 hours)	<1%, <3%, <5%	
Transverse mode	Multimode	
Dimensions of beam at the aperture (mm)	~5×8	
Beam divergence, full angle (mrad)	<3.0	
Warm-up time (minutes)	<5	
Beam height from base plate (mm)	24.8	
Operating temperature (°C)	10~35	
Power supply (85-264VAC)	PSU-III-LED	PSU-III-FDA
TTL / Analog modulation	TTL or Analog with 1Hz-1KHz, 1KHz-10KHz, 10KHz-30KHz optional	
Expected lifetime (hours)	10000	
Warranty	1 year	

